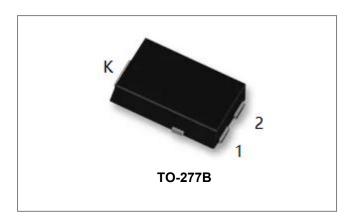






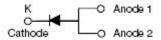
ST1550S SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	50	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C =80°C, rectangular wave form	15	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse, T _c = 25 °C	200	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*		@ 5A, Pulse, T _J = 25 °C	0.38	0.46	
	V_{F1}	@ 7.5A, Pulse, T _J = 25 °C	0.41	0.49	V
		@ 15A, Pulse, T _J = 25 °C	0.48	0.56	
		@ 5A, Pulse, T _J = 125 °C	0.26	0.35	
	V_{F2}	@ 7.5A, Pulse, T _J = 125 °C	0.31	0.40	V
		@ 15A, Pulse, T _J = 125 °C	0.41	0.50	
Reverse Current*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.14	3	mA
	I_{R2}	@V _R = rated V _R , T _J = 125 °C	60	140	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 \text{ °C} \\ f_{SIG} = 1MHz$	1100	-	pF

^{*} Pulse width < 300 μ s, duty cycle < 2%

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •



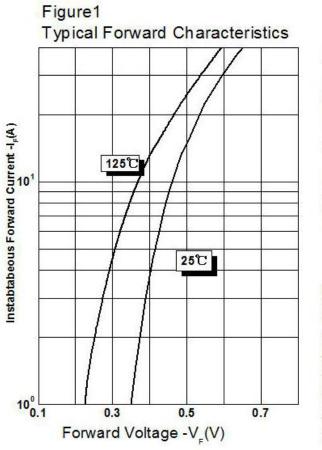


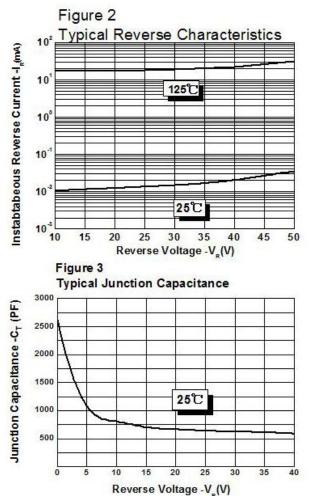


Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R ₀ JC	-	3.5	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$		70	°C/W
Approximate Weight	wt	-	0.08	g

Ratings and Characteristics Curves





[•] China - Germany - Korea - Singapore - United States •

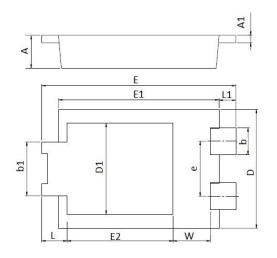
[•] http://www.smc-diodes.com - sales@ smc-diodes.com •

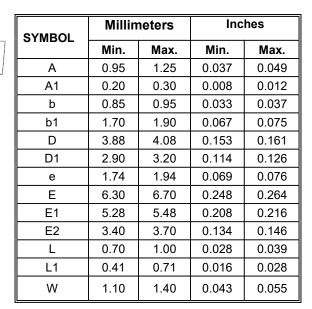




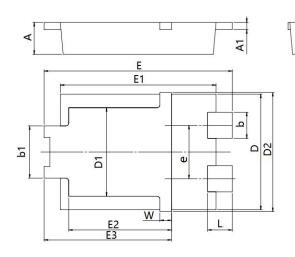


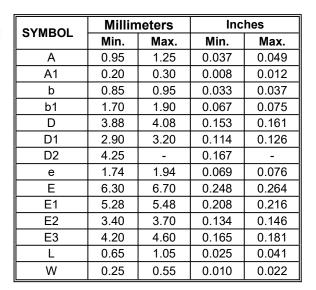
Mechanical Dimensions TO-277B





Mechanical Dimensions TO-277B(New)





Notes: New Mechanical Dimensions is performed from date code 2236X.

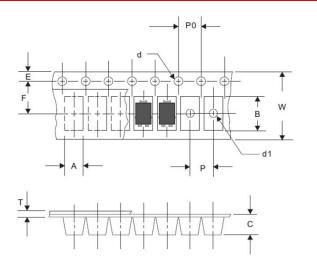
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Carrier Tape Specification TO-277B



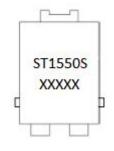
SYMBOL	Millimeters		
	Min.	Max.	
Α	4.28	4.48	
В	6.80	7.10	
С	1.30	1.50	
d	1.40	1.60	
d1	-	1.50	
E	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
Т	0.24	0.44	
W	11.70	12.30	

Ordering Information

Device	Package	Shipping
ST1550S	TO-277B	5000pcs/ reel
ST1550STR	TO-277B	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

ST = Device Type 15 = Forward Current (15A) 50 = Reverse Voltage (50V)

S = Package type YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

DISCLAIMER:

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